

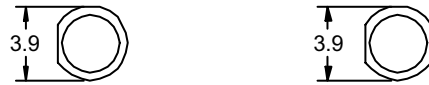


**BVU-3K0BE4**

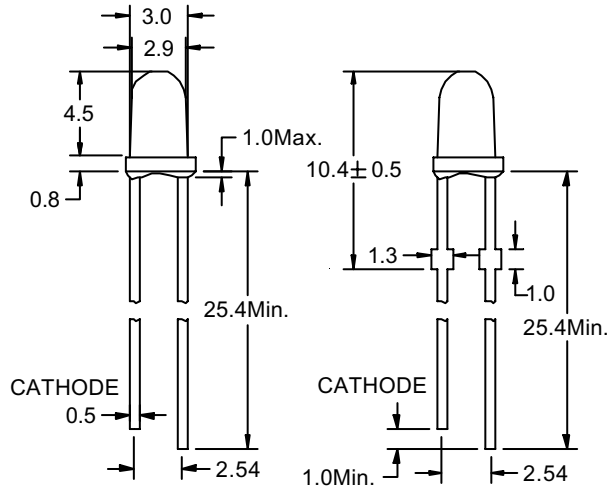
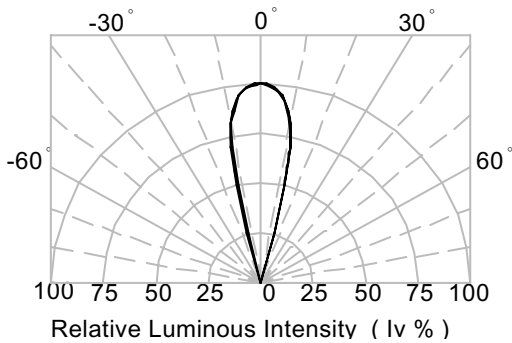
**PACKAGE CONFIGURATION**

**DESCRIPTION**

Dice Material : GaN/SiC Blue  
Light Color : Blue Color  
Lens Color : Water Transparent  
Stand-Off P/N : BVU-3K0BE4 R



**RADIATION PATTERN**



Tolerance ± 0.25 mm

**ABSOLUTE MAXIMUM RATINGS AT Ta = 25 °C**

PARAMETER	MAX.	UNIT
Power Dissipation	110	mW
Continuous Forward Current	30	mA
Peak Forward Current ( 1/10 Duty Cycle , 0.1ms Pulse Width )	70	mA
Reverse Voltage	5	V
Derating Linear From 50 °C	0.4	mA/°C
Operating Temperature Range	-40 °C to + 100 °C	
Storage Temperature Range	-40 °C to + 100 °C	
Lead Solder Temperature 1.6 mm Below Package	260 °C for 5 seconds	

**ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta = 25 °C**

SYMBOL	PARAMETER	TEST COND.	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 20 mA		3.8	4.7	V
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 5V			10	μA
λ <sub>p</sub>	Peak Emission Wavelength	I <sub>F</sub> = 20 mA		428		nm
λ <sub>d</sub>	Dominant Wavelength	I <sub>F</sub> = 20 mA		466		nm
2θ <sub>1/2</sub>	Viewing Angle	I <sub>F</sub> = 20 mA		25		Deg

**BIN GRADE LIMITS ( I F = 20 mA ) LUMINOUS INTENSITY / mcd**

Bin	y	z	A	B	C	D
Min.	60	78	100	130	168	218
Max.	78	100	130	168	218	280

Tolerance ± 15% mcd

\*Bright View reserves the rights to alter specifications and remove availability of products at any time without notice.

\*Dominant Wavelength, λ<sub>d</sub> is according to CIE Chromaticity Diagram base on color of lamps.

\*θ<sub>1/2</sub> is the off-axis angle where the luminous intensity is one half the on-axis intensity.

\*These products are sensitive to static electricity. Caution must be taken strictly to avoid static electricity.



# GaN/SiC Blue LED

## TYPICAL ELECTRICAL/OPTICAL CHARACTERISTIC CURVES

FIG. 1 Forward Current Vs. Forward Voltage

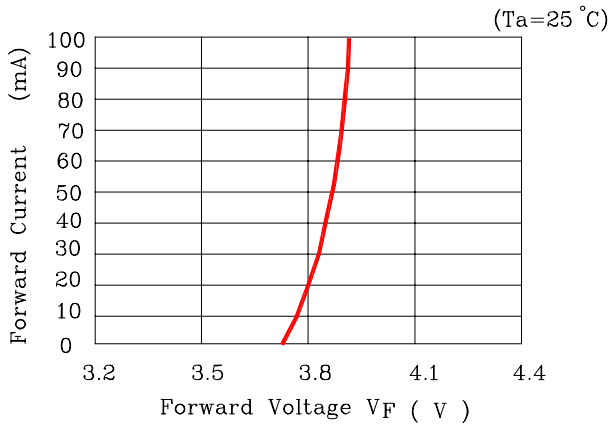


FIG. 2 Relative Intensity Vs. Forward Current

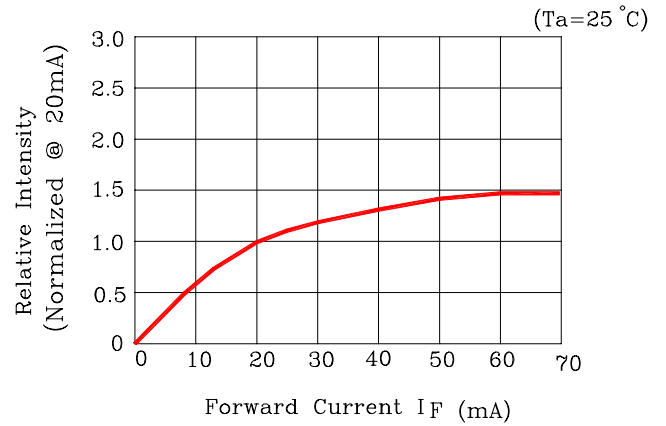


FIG. 3 Forward Voltage VS. Temperature

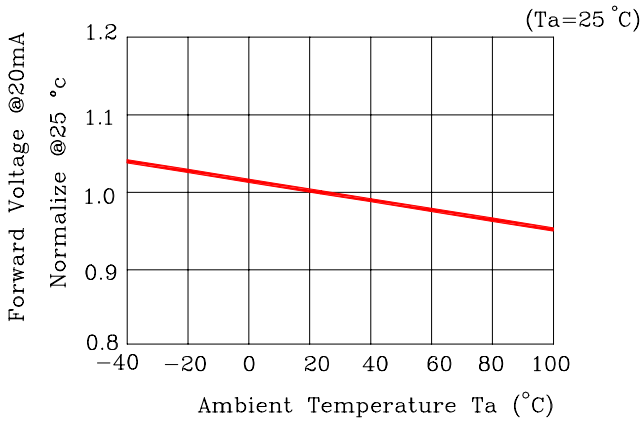


FIG. 4 Relative Intensity vs. Temperature

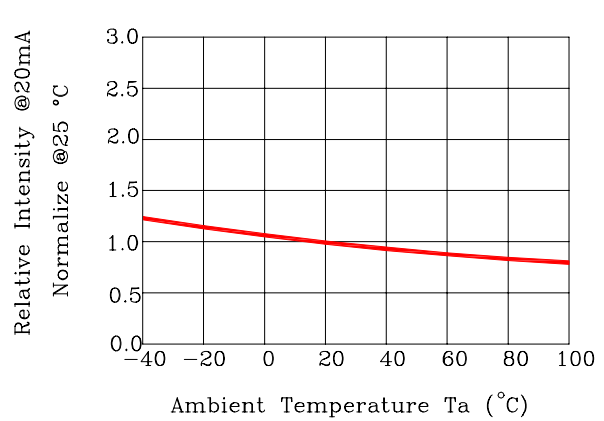


FIG. 5 Relative Intensity vs. Wavelength ( $\lambda_p$ )

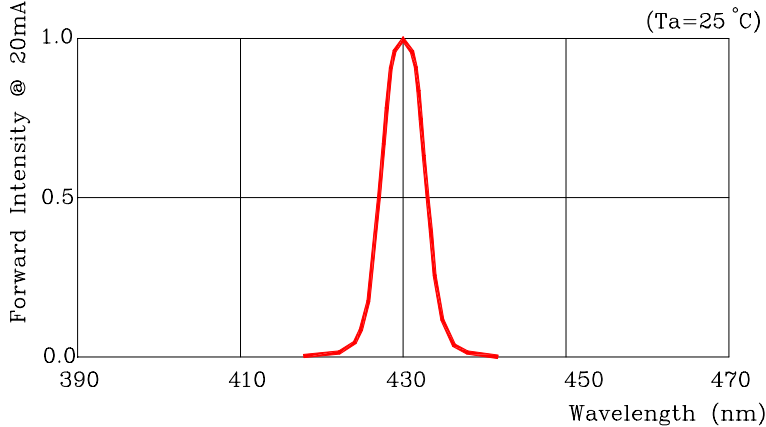
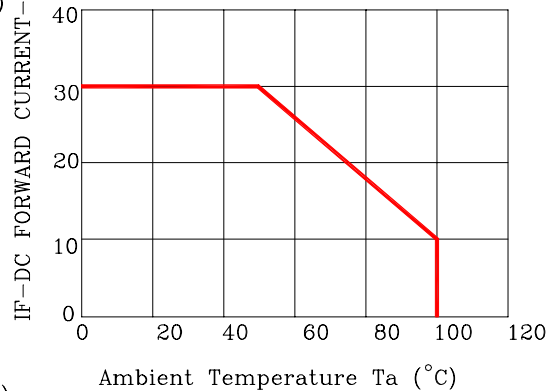


FIG. 6 Maximum Forward Current vs. Ambient Temperature. Derating Based on  $T_{JMAX}=130^{\circ}C$





## CAUTION FOR STATIC ELECTRICITY

### 靜電防治

These products are Gallium Nitride(GaN) or Indium Gallium Nitride(InGaN) light emitting diodes(LEDs). There are extremely sensitive to static electricity ESD damage. The user must take absolutely secure countermeasures against static electricity and surge when handling products.

顯明 LED 晶片材質為 Gallium Nitride(GaN)或 Indium Gallium Nitride(InGaN) , 此材質對於靜電極為敏感 , 十分容易受靜電衝擊而產生破壞 , 使用者接觸產品時必需做好對靜電衝擊之防護措施。

Bright View Blue, Green are GaN/ Sic or InGaN/ Sic materials are ESD classified, any manufacturing or workstations where GaN/ Sic or InGaN/ Sic devices are handled should be rated at "Class 2" 100V maximum.

顯明之藍、綠光晶片材質為 GaN/Sic 或 InGaN/ Sic , 此材質屬 ESD 規範 , 任何 GaN/ Sic 或 InGaN/ Sic 產品所會被接觸的製造或工作站必須控制在 100V 以下。

Proper grounding of products (via 1M  $\Omega$  ), use of conductive mat, semiconductive working uniform and shoes, and semiconductive containers are considered to be effective as countermeasures against static electricity and surge.

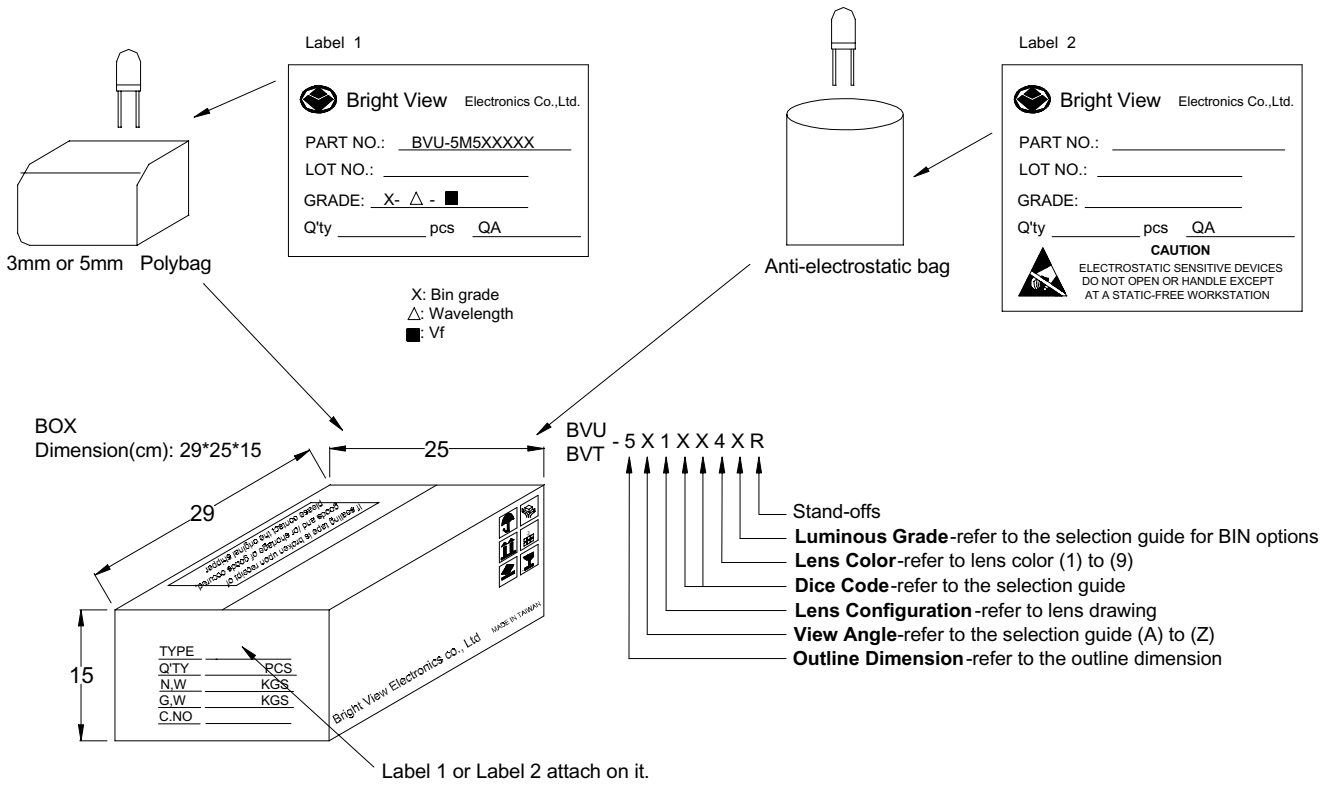
適當的產品接地 ( 1M  $\Omega$  ) 與使用導電桌墊 , 並評估考慮穿著防靜電工作服、防靜電鞋與防靜電盒來有效地防制靜電之衝擊。

An ionizer is recommended to be used in the facility or environment where static electricity may be generated easily, and soldering iron with a grounded tip is also recommended.

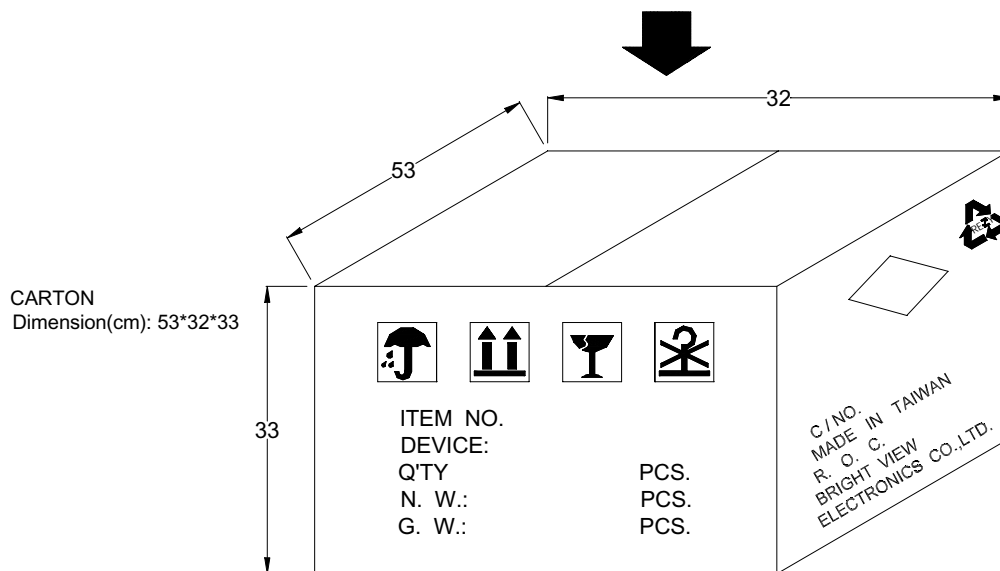
建議對於工廠設施與環境中容易產生靜電的地點使用離子風扇吹拂 , 且也建議使用有接地功能的烙鐵進行焊接。

To install a protection device, in the LED driving circuit, which does not exceed the max rating for surge current during on/off switching.

在驅動 LED 的電路上設置保護裝置 , 使其當開閉時的瞬間電流不會超出最大電壓值。



Device	Q'ty / Polybag (pcs)	Polybag / Box A	Fig.
5mm(T-1 3/4)	1000pcs	14 bags	Label 1
3mm(T-1)	1000pcs	20 bags	Label 1
Blue / Green / White	500pcs	18 bags	Label 2



4 Boxes / Carton

5mm : 56,000pcs

3mm : 80,000pcs

Blue / Green / White : 36,000pcs